GF22: 3.3V GPIO

AUTOMOTIVE GRADE

Libraries

Name	Process	Form Factor
RGO_GF22_18V33_FDX_25C	FDX	Staggered CUP
RGO_GF22_18V33_FDX_45C	FDX	Inline CUP

Summary

The 3.3V GPIO library provides general purpose bidirectional I/O cells. These programmable, multi-voltage I/O's give the system designer the flexibility to design to a wide range of performance targets.

These 22nm libraries are available in inline and staggered CUP wire bond implementations with a flip chip option.

To design a functional I/O power domain with these cells, an additional library is required – 3.3V Support: Power. That library contains an input-only buffer, isolated analog I/O, and a full complement of power cells along with corner and spacer cells to assemble a complete pad ring by abutment. An included rail splitter allows multiple power domains to be isolated in the same pad ring while maintaining continuous VDD/VSS for robust ESD protection.

ESD Protection:

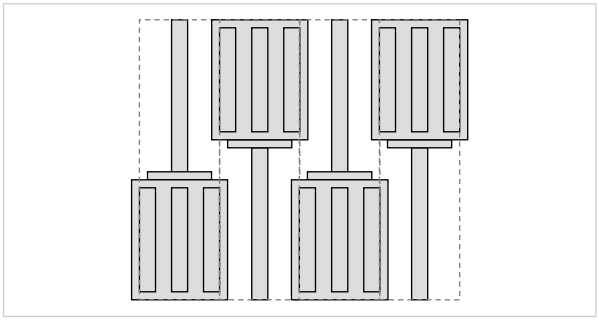
- JEDEC compliant
  - 2KV ESD Human Body Model (HBM)
  - 500 V ESD Charge Device Model (CDM)
    - 750V corner pin C4B package classification achieved by following key design priorities

Latch-up Immunity:

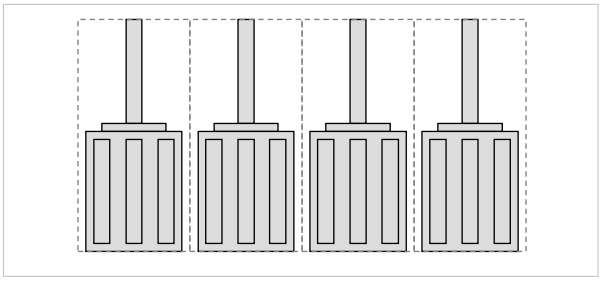
- JEDEC compliant
  - Tested to I-Test criteria of ± 100mA @ 125°C

Cell Size & Form Factor

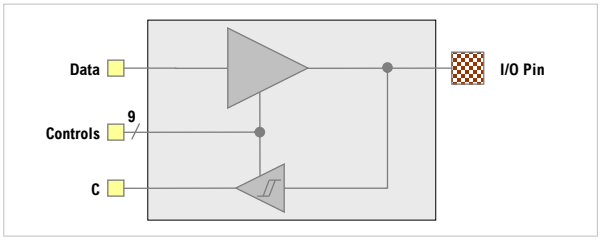
Staggered (pad-limited) – 30µm x 165µm



Inline (core-limited) – 52µm x 95µm



SRx_BI_SDS_1833V_STB



Bidirectional GPIO Driver Features

- Multi-Voltage (1.2V, 1.5V, 1.8V, 2.5V, 3.3V)
- LVCMOS / LVTTL input with selectable hysteresis
- Programmable drive strength (rated 2mA to 12mA)
- Selectable output slew rate
- Optimized for EMC with SSO factor of 8
- Open-drain output mode
- Programmable input options (pull-up/pull-down/repeater)
- Power-On Start (POS) capable
- Power sequencing independent design with Power-On Control

In full-drive mode, this driver can operate to frequencies in excess of 100MHz with 15pF external load and 125 MHz with 10pF load. Actual frequency limits are load and system dependent. A maximum of 200 MHz can be achieved under small capacitive loads.

Vertical-only (_V) and and horizontal-only (_H) variants provided.

Recommended operating conditions

	Description	Min	Nom	Max	Units
V_{VDD}	Core supply voltage	0.81	0.9	0.945	V
		0.72	0.8	0.88	V
V_{DVDD}	I/O supply voltage	2.97	3.3	3.63	V
		2.25	2.5	2.75	V
		1.62	1.8	1.98	V
		1.35	1.5	1.65	V
		1.08	1.2	1.32	V
T_J	Junction temperature	-40	25	150	°C
V_{PAD}	Voltage at PAD	V_{DVSS} -0.3	-	V_{DVDD} +0.3	V

Characterization Corners

Nominal VDD	Model	VDD	DVDD[1]	Temperature
0.8V (AG2)	FFG	+10%	+10%	-40°C
	FFG	+10%	+10%	125°C
	TT	nominal	nominal	25°C
	TT	nominal	nominal	85°C
	SSG	-10%	-10%	-40°C
	SSG	-10%	-10%	125°C
0.9V Overdrive (AG2)	FFG	+5%	+10%	-40°C
	FFG	+5%	+10%	125°C
	TT	nominal	nominal	25°C
	TT	nominal	nominal	85°C
	SSG	-10%	-10%	-40°C
	SSG	-10%	-10%	125°C
0.8V (AG1)	FFG	+5%	+10%	-40°C
	FFG	+5%	+10%	125°C
	FFG	+5%	+10%	150°C
	SSG	-10%	-10%	150°C

[1] DVDD = 1.2V, 1.5V, 1.8V, 2.5V & 3.3V

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